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In Re Application of: Anderson et al.

Conf. No.:

1115

Serial No.:

10/604,116

Art Unit:

2823

Filed:

06/26/2003

Dkt. No.: BUR920030031US1 (TBMB-0028)

Title: METHOD OF FORMING

Examiner:

Garcia, Joannie A

FREESTANDING

SEMICONDUCTOR LAYER

COMMISSIONER FOR PATENTS

DESTINATION FACSIMILE NUMBER:

571-273-8300

Transmitted herewith is:

Amendment (12 pgs.)

in the above identified application.

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Joannie A. Garcia

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LAYER

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

AMENDMENT

Sir:

I. INTRODUCTORY COMMENTS

In response to the Office Communication of November 1, 2005 and the Office Action of May 27, 2005, please amend the above-referenced patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims that begins on page 3 of this paper.

Remarks begin on page 9 of this paper.

10/604,116

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